## NSN 5962-01-351-9524

Memory Microcircuit - Page 1 of 2

Overall Height: 0.400 inches Body Length: 1.280 inches Body Width:



View Online at https://aerobasegroup.com/nsn/5962-01-351-9524

Between 0.220 inches and 0.310 inches
Body Height:
Between 0.140 inches and 0.185 inches
Maximum Power Dissipation Rating:
1.02 watts
Operating Tempurature Range:
-55.0/+125.0 degrees celsius
Storage Tempurature Range:
-65.0/+150.0 degrees celsius
End Application:
Satellite communications terminal an/usc-3 (v) 1
Features Provided:
Hermetically sealed and burn in and monolithic and programmed
Inclosure Material:
Ceramic
Inclosure Configuration:
Dual-in-line
Output Logic Form:
Transistor-transistor logic
Input Circuit Pattern:
14 input
Case Outline Source And Designator:
D-9 mil-m-38510
Current Rating Per Characteristic:
185.00 milliamperes reverse current, dc absolute
Terminal Surface Treatment:
Solder
Voltage Rating And Type Per Characteristic:
-0.5 volts power source and 7.0 volts power source
Capitance Rating Per Characteristic:
8.00 input pascal industrial light tank stock and 15.00 output pascal industrial light tank stock
Time Rating Per Chacteristic:
25.00 nanoseconds delay
Memory Device Type:
Prom
Test Data Document:
96906-mil-std-883 standard (includes industry or association standards, individual manufactureer standards, etc.)

## NSN 5962-01-351-9524

Memory Microcircuit - Page 2 of 2



Terminal Type A	nd Quantity:
-----------------	--------------

24 printed circuit

Shelf Life:

N/a

**Unit Of Measure:** 

--

Demilitarization:

Yes - demil/mli

Fiig:

A458a0